NEC

HIGH COLLECTOR TO EMITTER VOLTAGE 4 PIN ULTRA SMALL FLAT LEAD OPTOCOUPLER

PS2932-1 PS2933-1

FEATURES

- ULTRA SMALL FLAT LEAD PACKAGE: 4.6 (L) x 2.5 (W) x 2.1 (H) mm
- ISOLATION DISTANCE: 0.4 mm MIN
- HIGH COLLECTOR TO EMITTER VOLTAGE:

VCEO = 300 V: PS2932-1 VCEO = 350 V: PS2933-1

• HIGH ISOLATION VOLTAGE

BV = 2500 Vr.m.s.

• AVAILABLE ON TAPE AND REEL:

PS2932-1-F3, F4: 3500 pcs/reel PS2933-1-F3, F4: 3500 pcs/reel

DESCRIPTION

The PS2932-1 and PS2933-1 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in one package for high density mounting applications. This device is housed in an ultra-small flat-lead package which realizes a reduction in mounting area of about 30% compared to the PS28xx series.

APPLICATIONS

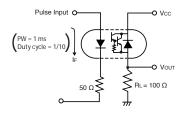
- HYBRID IC
- TELEPHONE, EXCHANGE EQUIPMENT, FAX

ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER						PS2932-1, PS2933-1		
SYMBOLS		PARAMETERS		UNITS	MIN	TYP	MAX	
Diode	VF	Forward Voltage, IF = 1 mA		V	0.9	1.1	1.3	
	IR	Reverse Current, VR = 5 V		μΑ			5	
	Ст	Terminal Capacitance, V = 0 V, f = 1.0 MHz		pF		15		
Transistor	ICEO	Collector to Emitter Current, VcE = 300 V (350 V) ¹		nA			400	
Coupled	CTR	Current Transfer Ratio (Ic/IF), IF = 1 mA, VCE = 2 V		%	400	2000	4500	
	VCE(sat)	Collector Saturation Voltage, IF = 1 mA, IC = 2 mA		V		0.8	1	
	Rı-o	Isolation Resistance, VI-O = 1.0 kVDC		Ω	10 ¹¹			
	Cı-o	Isolation Capacitance, V = 0 V, f = 1.0 MHz		pF		0.4		
	tr	Rise Time ²	Vcc = 5 V, Ic = 10 mA, RL = 100 Ω	μS		20		
	tF	Fall Time ²		μ\$		5		

Notes

- 1. Iceo condition : PS2932-1: VcE = 300 V: PS2933-1: VcE = 350 V:
- 2. Test circuit for switching time:



ABSOLUTE MAXIMUM RATINGS¹

(TA = 25°C unless otherwise specified)

SYMBOLS	SYMBOLS PARAMETERS		RATINGS			
Diode						
lF	Forward Current (DC)	mA	50			
ΔIF/°C	Forward Current Derating	mA/°C	0.5			
IF (Peak)	IF (Peak) Peak Forward Current ²		0.5			
PD	PD Power Dissipation		60			
VR	VR Reverse Voltage		6			
Transistor						
VCEO	Collector to Emitter Voltage PS2932-1	V	300			
	PS2933-1		350			
VECO	Emitter to Collector Voltage	V	0.3			
Ic	Collector Current	mA	60			
Pc	Power Dissipation	mW	120			
ΔPc/°C	ΔPc/°C Power Dissipation Derating		1.2			
Coupled						
Viso	Isolation Voltage ³	Vr.m.s.	2500			
PT Total Power Dissipation		mW	160			
Ta Operating Ambient Temp.		°C	-55 to +100			
Tstg Storage Temperature		°C	-55 to +150			

Notes:

- Operation in excess of any one of these parameters may result in permanent damage.
- 2. PW = 100 μs, Duty Cycle = 1%.
- 3. AC voltage for 1 minute at TA = 25°C, RH = 60 % between input and output.

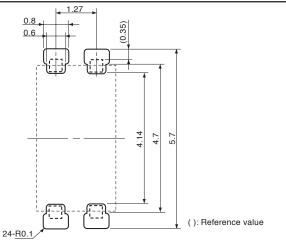
CAUTIONS REGARDING NOISE:

Be aware that when voltage is applied suddenly between the optocoupler's input and outout or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

ORDERING INFORMATION

PART NUMBER	PACKING STYLE
PS29132-1-F3	Embossed Tape 3500 pcs/reel
PS2932-1-F4	
PS29133-1-F3	
PS29133-1-F4	

RECOMMENDED MOUNT PAD DIMENSIONS (Units in mm)



Remark:

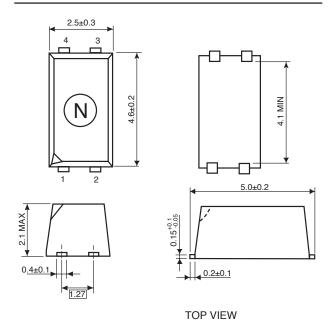
This drawing is considered to meet air and outer creepage distance

4.0 mm minimum. All simensions in this figure must be evaluated before use.

OPTOCOUPLER CONSTRUCTION

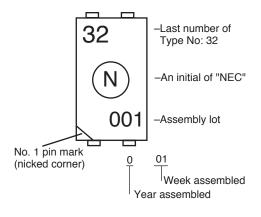
PARAMETER	UNIT (MIN)
Air Distance	4 mm
Creepage Distance	4 mm
Isolation Distance	0.4 mm

OUTLINE DIMENSIONS (Units in mm)

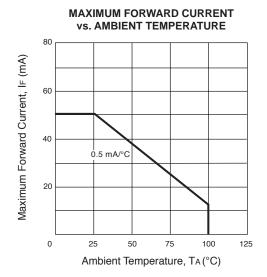


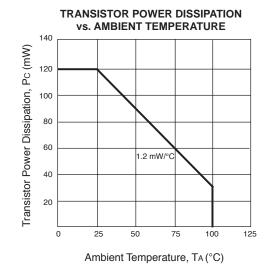
- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

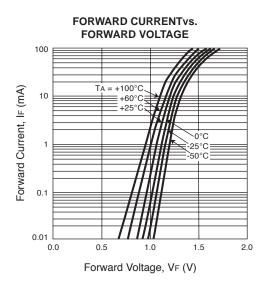
MARKING

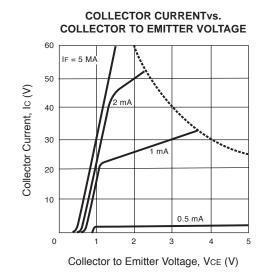


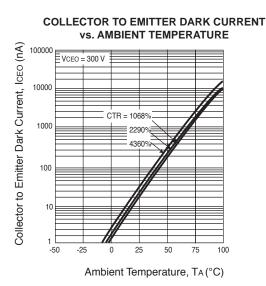
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

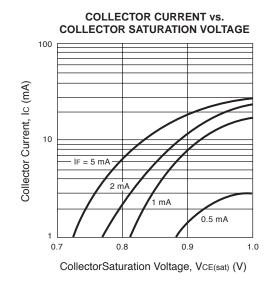






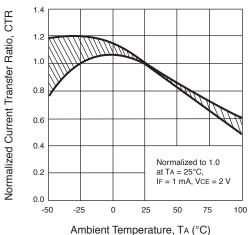






TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)





Current Transfer Ratio, CTR (%) 3000 2500 2000 1500 1000

4000

3500

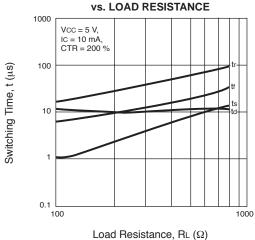
500

VCE = 2 V

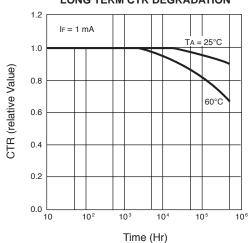
CURRENT TRANSFER RATIO vs. FORWARD CURRENT

Forward Current, IF (mA)

SWITCHING TIME



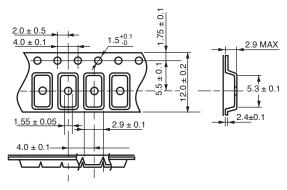
LONG TERM CTR DEGRADATION



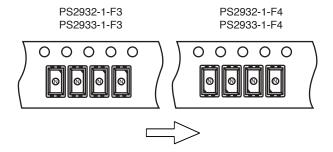
REMARK: The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (Units in mm)

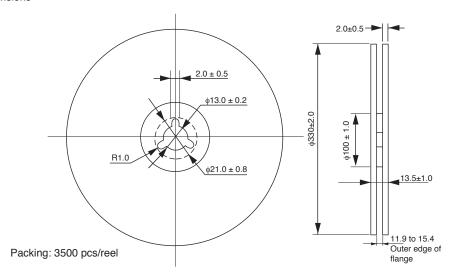
Tape Outline and Dimensions



Tape Direction



Reel Outline and Dimensions



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

Peak reflow temperature 260 °C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220 °C 60 seconds or less

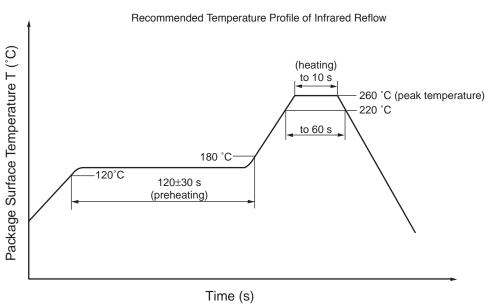
Time to preheat temperature from 120 to 180°C

120±30 s Number of reflows Three

Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is

recommended).



(2) Wave soldering

Temperature 260 °C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt % is recommended).

(3) Cautions

 Fluxes Avoid removing the residual flux with chlorine-based cleaning solvent after a reflow process.

USAGE CAUTIONS

- 1. Protect against static electricity when handling
- 2. Avoid storage at a high temperature ad high humidity.

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.